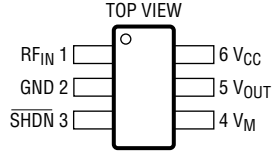


ABSOLUTE MAXIMUM RATINGS

(Note 1)

| | |
|--|-----------------------------|
| V_{CC} , V_{OUT} , \overline{SHDN} , V_M | –0.3V to 6.5V |
| RF_{IN} Voltage | ($V_{CC} \pm 1.5V$) to 7V |
| RF_{IN} Power (RMS) | 12dBm |
| I_{VOUT} | 5mA |
| Operating Temperature Range (Note 2) .. | –40°C to 85°C |
| Maximum Junction Temperature | 125°C |
| Storage Temperature Range | –65°C to 150°C |
| Lead Temperature (Soldering, 10 sec) | 300°C |

PACKAGE/ORDER INFORMATION

| | |
|---|-------------------|
|  <p>S6 PACKAGE 6-LEAD PLASTIC TSOT-23 $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 250^{\circ}C/W$</p> | ORDER PART NUMBER |
| | LTC5530ES6 |
| | S6 PART MARKING |
| | LBDX |

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_{CC} = 3.6V$, $\overline{SHDN} = V_{CC} = HI$, $\overline{SHDN} = 0V = LO$, RF Input Signal is Off, $R_A = R_B = 1k$, $\overline{SHDN} = HI$ unless otherwise noted.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|---|--|------|-----------------|-----------------|-------------------|
| V_{CC} Operating Voltage | ● | 2.7 | | 6 | V |
| I_{VCC} Operating Current | $I_{VOUT} = 0mA$ ● | | 0.5 | 0.7 | mA |
| I_{VCC} Shutdown Current | $\overline{SHDN} = LO$ ● | | 0.01 | 2 | μA |
| V_{OUT} (No RF Input) | $R_{LOAD} = 2k$ ● $\overline{SHDN} = LO$ | 85 | 100 to 140 1 | 155 | mV mV |
| V_{OUT} Output Current | $V_{OUT} = 1.75V$, $V_{CC} = 2.7V$, $\Delta V_{OUT} < 10mV$ ● | 2 | 4 | | mA |
| V_{OUT} Enable Time | $\overline{SHDN} = LO$ to HI , $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ ● | | 8 | 20 | μs |
| V_{OUT} Bandwidth | $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ (Note 4) | | 2 | | MHz |
| V_{OUT} Load Capacitance | (Notes 6, 7) ● | | | 33 | pF |
| V_{OUT} Slew Rate | $V_{RFIN} = 1V$ Step, $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ (Note 3) | | 3 | | V/ μs |
| V_{OUT} Noise | $V_{CC} = 3V$, Noise BW = 1.5MHz, 50 Ω RF Input Termination | | 1 | | mV _{P-P} |
| V_M Voltage Range | ● | 0 | | $V_{CC} - 1.8V$ | V |
| V_M Input Current | ● | –0.5 | | 0.5 | μA |
| \overline{SHDN} Voltage LO, Chip Disabled | $V_{CC} = 2.7V$ to 6V ● | | | 0.35 | V |
| \overline{SHDN} Voltage HI, Chip Enabled | $V_{CC} = 2.7V$ to 6V ● | 1.4 | | | V |
| \overline{SHDN} Input Current | $\overline{SHDN} = 3.6V$ ● | | 22 | 36 | μA |
| RF_{IN} Input Frequency Range | (Note 8) | | 300 to 7000 | | MHz |
| RF_{IN} Input Power Range | RF Frequency = 300MHz to 7GHz (Note 5, 6) $V_{CC} = 2.7V$ to 6V | | –32 to 10 | | dBm |
| RF_{IN} AC Input Resistance | $F = 1000MHz$, $P_{in} = -25dBm$ | | 220 | | Ω |
| RF_{IN} Input Shunt Capacitance | $F = 1000MHz$, $P_{in} = -25dBm$ | | 0.65 | | pF |

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: The rise time at V_{OUT} is measured between 1.3V and 2.3V.

Note 4: Bandwidth is calculated based on the 10% to 90% rise time

equation: $BW = 0.35/\text{rise time}$.

Note 5: RF performance is tested at 1800MHz

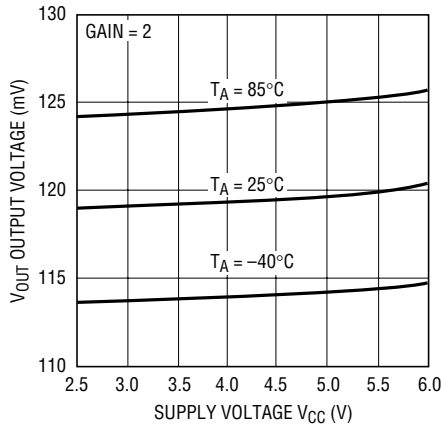
Note 6: Guaranteed by design.

Note 7: Capacitive loading greater than this value may result in circuit instability.

Note 8: Higher frequency operation is achievable with reduced performance. Consult factory for more information.

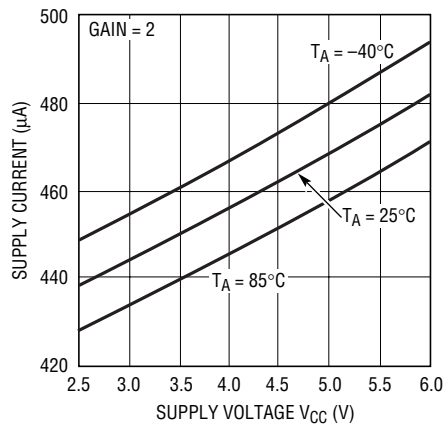
TYPICAL PERFORMANCE CHARACTERISTICS

Output Voltage vs Supply Voltage
(RF Input Signal Off)



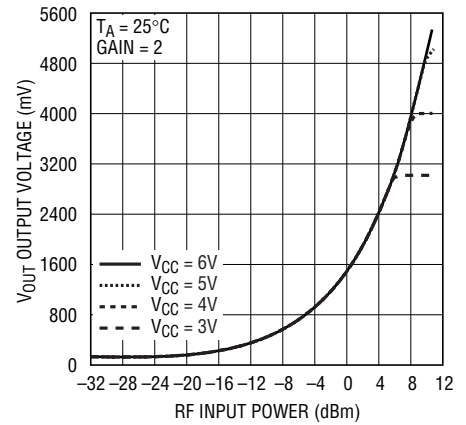
5530 G01

Supply Current vs Supply Voltage
(RF Input Signal Off)



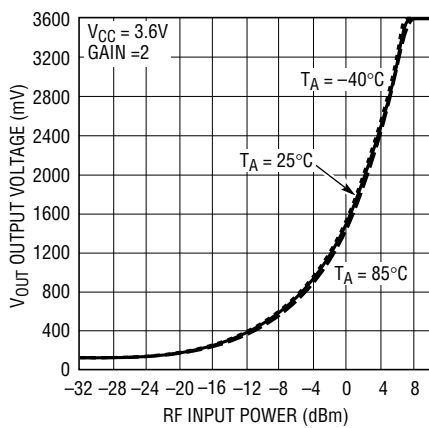
5530 G02

V_{OUT} vs RF Input Power and V_{CC}
1000MHz



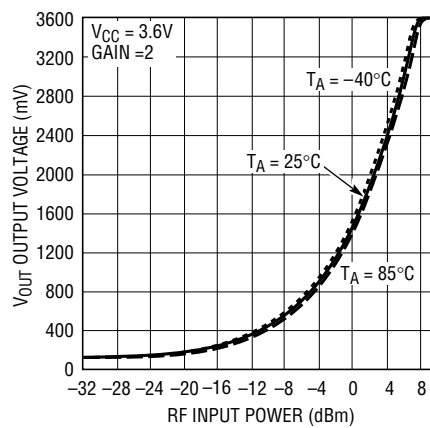
5530 G03

Typical Detector Characteristics,
300MHz



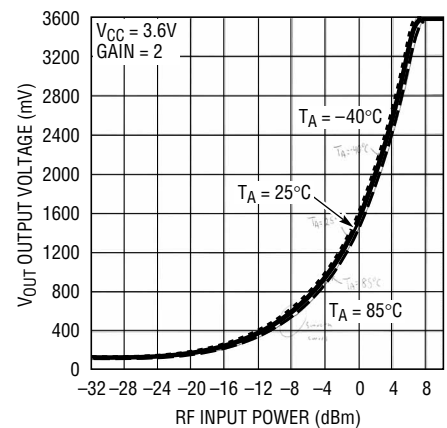
5530 G04

Typical Detector Characteristics,
1000MHz



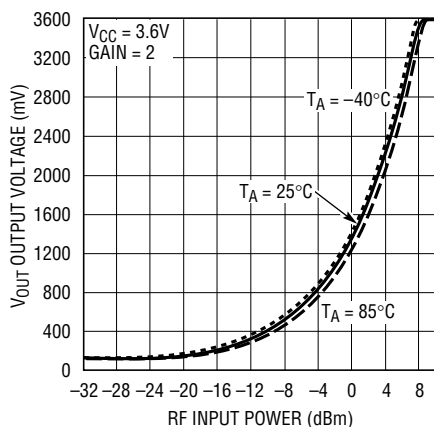
5530 G05

Typical Detector Characteristics,
2000MHz



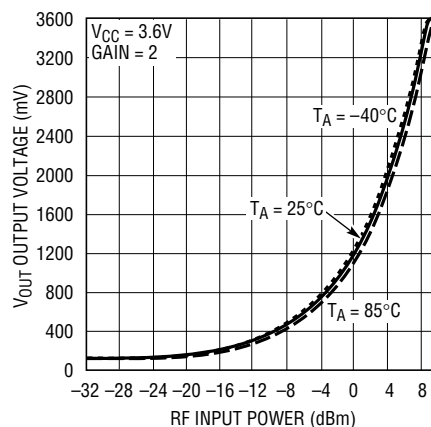
5530 G06

Typical Detector Characteristics,
3000MHz



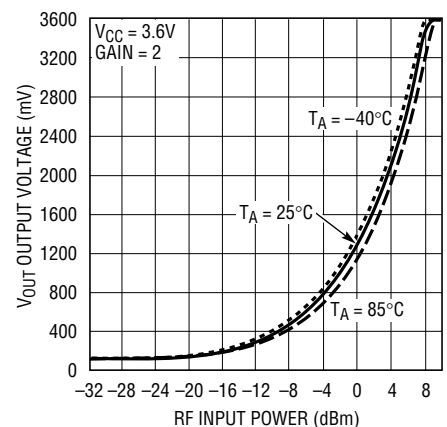
5530 G07

Typical Detector Characteristics,
4000MHz



5530 G08

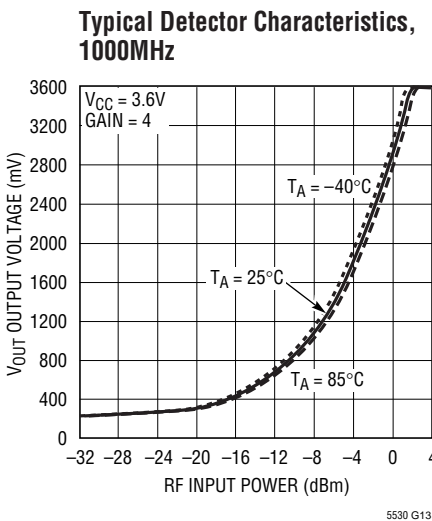
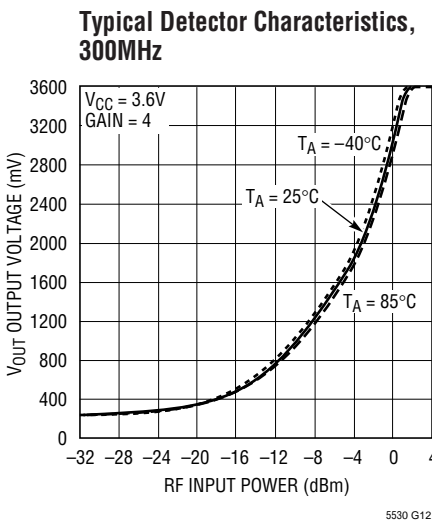
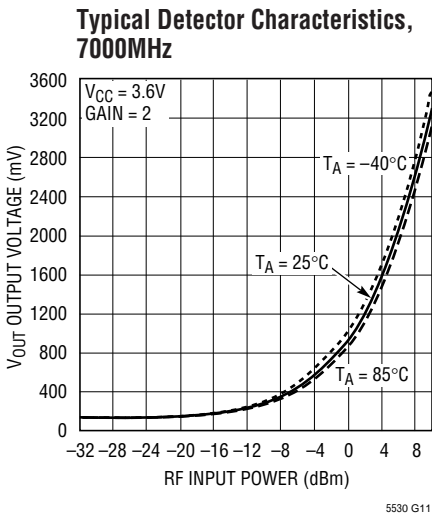
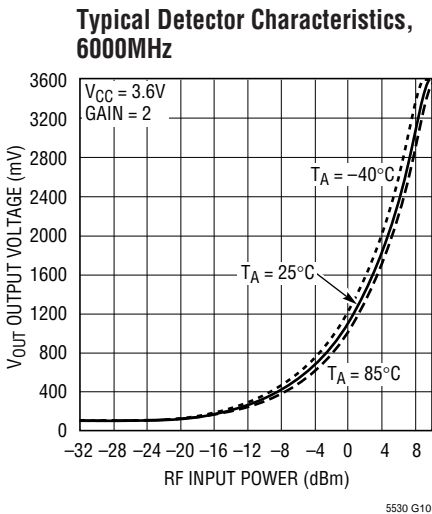
Typical Detector Characteristics,
5000MHz



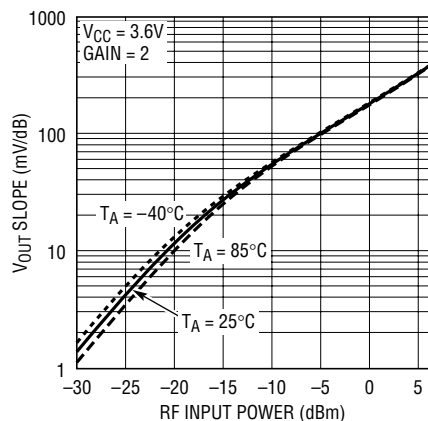
5530 G09

5530f

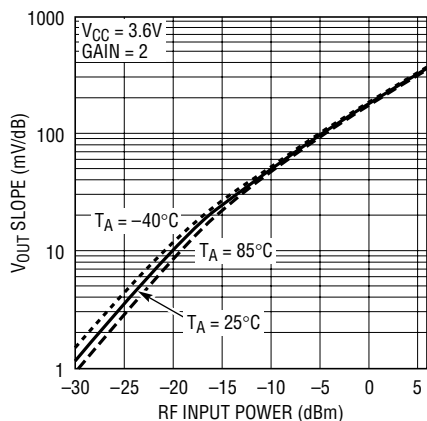
TYPICAL PERFORMANCE CHARACTERISTICS



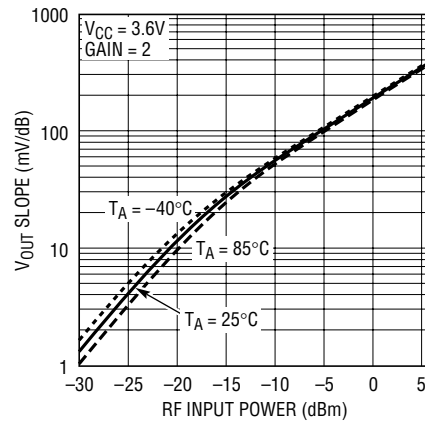
TYPICAL PERFORMANCE CHARACTERISTICS

V_{OUT} Slope vs RF Input Power
300MHz

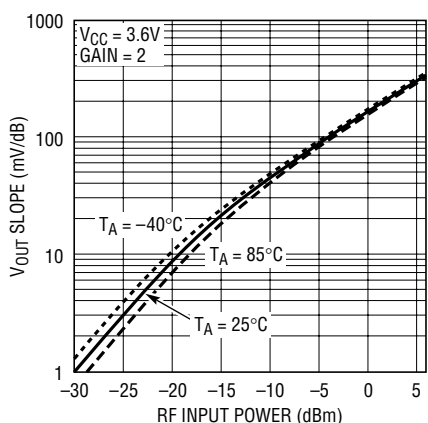
5530 G14

V_{OUT} Slope vs RF Input Power
1000MHz

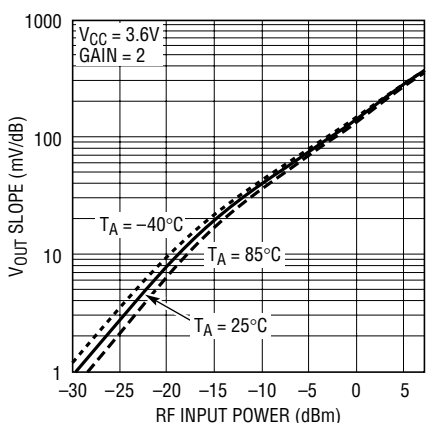
5530 G15

V_{OUT} Slope vs RF Input Power
2000MHz

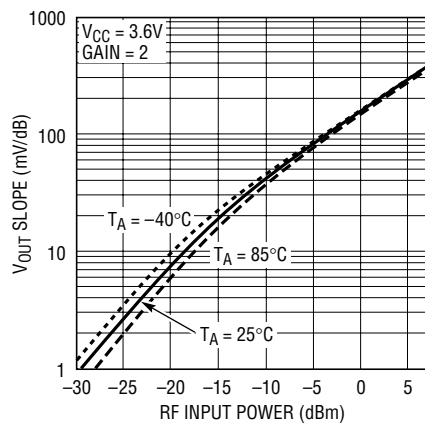
5530 G16

V_{OUT} Slope vs RF Input Power
3000MHz

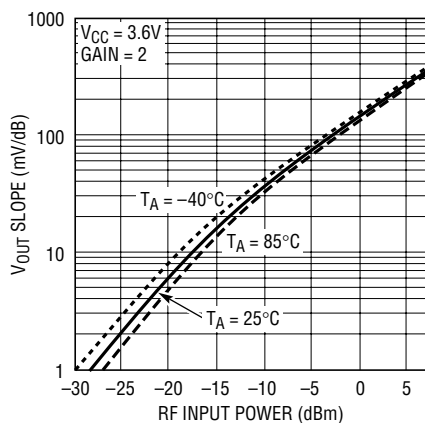
5530 G17

V_{OUT} Slope vs RF Input Power
4000MHz

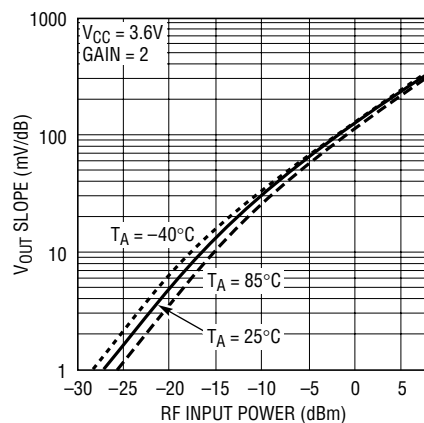
5530 G18

V_{OUT} Slope vs RF Input Power
5000MHz

5530 G19

V_{OUT} Slope vs RF Input Power
6000MHz

5530 G20

V_{OUT} Slope vs RF Input Power
7000MHz

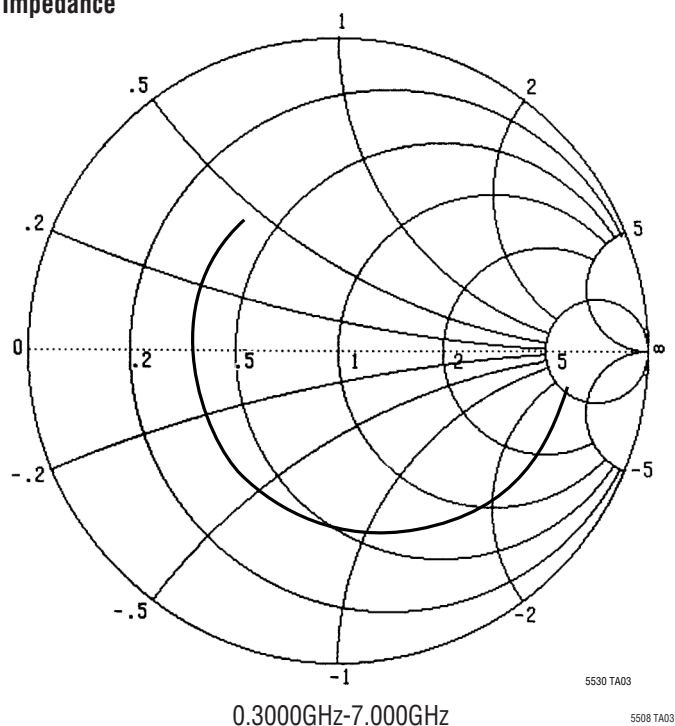
5530 G21

TYPICAL PERFORMANCE CHARACTERISTICS

RF_{IN} Input Impedance (Pin = 0dBm, V_{CC} = 3.6V, T_A = 25°C)

| FREQUENCY (GHz) | RESISTANCE (Ω) | REACTANCE (Ω) |
|--------------------|-------------------|------------------|
| 0.30 | 290.45 | -136.22 |
| 0.50 | 234.41 | -162.54 |
| 0.70 | 178.25 | -170.53 |
| 0.90 | 137.31 | -159.89 |
| 1.10 | 109.17 | -147.57 |
| 1.30 | 86.30 | -136.18 |
| 1.50 | 68.65 | -121.74 |
| 1.70 | 57.48 | -107.60 |
| 1.90 | 49.79 | -96.72 |
| 2.10 | 43.56 | -86.70 |
| 2.30 | 38.67 | -77.91 |
| 2.50 | 34.82 | -70.13 |
| 2.70 | 31.68 | -62.86 |
| 2.90 | 29.13 | -56.01 |
| 3.10 | 27.17 | -49.83 |
| 3.30 | 25.73 | -44.24 |
| 3.50 | 24.56 | -39.74 |
| 3.70 | 23.18 | -35.35 |
| 3.90 | 22.31 | -30.62 |
| 4.10 | 20.73 | -26.88 |
| 4.30 | 19.88 | -22.31 |
| 4.50 | 19.40 | -18.23 |
| 4.70 | 19.05 | -14.25 |
| 4.90 | 19.08 | -10.21 |
| 5.10 | 19.55 | -6.30 |
| 5.30 | 20.85 | -2.84 |
| 5.50 | 21.94 | -1.49 |
| 5.70 | 20.60 | -0.07 |
| 5.90 | 19.29 | 2.99 |
| 6.10 | 18.69 | 6.61 |
| 6.30 | 18.53 | 10.39 |
| 6.50 | 18.74 | 14.35 |
| 6.70 | 19.79 | 17.91 |
| 6.90 | 19.75 | 20.77 |
| 7.00 | 19.99 | 22.47 |

S11 Forward Reflection
Impedance

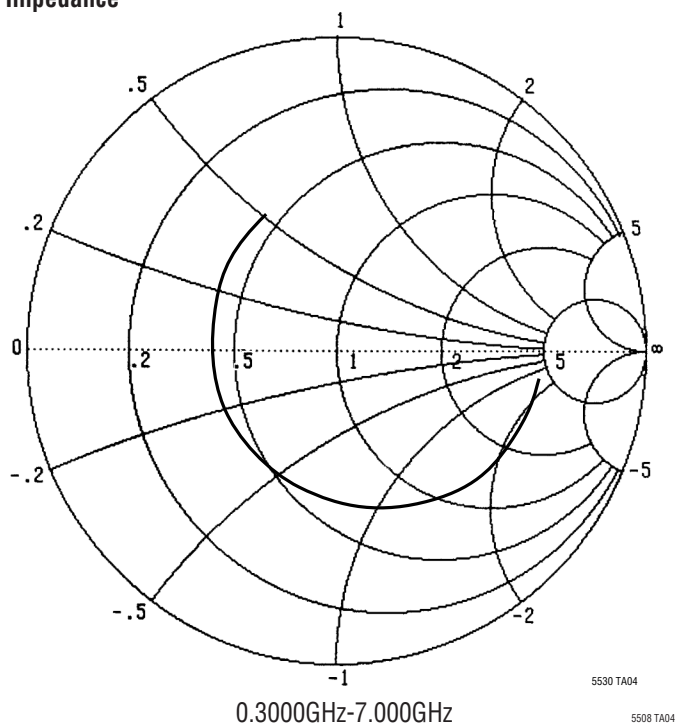


TYPICAL PERFORMANCE CHARACTERISTICS

RF_{IN} Input Impedance (Pin = -25dBm, V_{CC} = 3.6V, T_A = 25°C)

| FREQUENCY (GHz) | RESISTANCE (Ω) | REACTANCE (Ω) |
|--------------------|-------------------|------------------|
| 0.30 | 216.45 | -76.47 |
| 0.50 | 190.63 | -98.28 |
| 0.70 | 161.98 | -112.03 |
| 0.90 | 133.17 | -111.53 |
| 1.10 | 113.08 | -109.05 |
| 1.30 | 94.55 | -107.08 |
| 1.50 | 75.33 | -98.50 |
| 1.70 | 63.52 | -88.19 |
| 1.90 | 55.19 | -80.05 |
| 2.10 | 48.64 | -72.23 |
| 2.30 | 43.73 | -64.81 |
| 2.50 | 39.71 | -58.31 |
| 2.70 | 36.47 | -52.27 |
| 2.90 | 33.69 | -46.77 |
| 3.10 | 31.61 | -41.25 |
| 3.30 | 29.78 | -36.61 |
| 3.50 | 28.27 | -32.39 |
| 3.70 | 26.63 | -28.12 |
| 3.90 | 26.12 | -23.97 |
| 4.10 | 24.20 | -20.75 |
| 4.30 | 23.28 | -16.69 |
| 4.50 | 22.60 | -12.77 |
| 4.70 | 22.21 | -9.08 |
| 4.90 | 22.15 | -5.24 |
| 5.10 | 22.61 | -1.58 |
| 5.30 | 23.90 | 1.53 |
| 5.50 | 24.97 | 2.62 |
| 5.70 | 23.51 | 4.00 |
| 5.90 | 22.25 | 6.94 |
| 6.10 | 21.57 | 10.62 |
| 6.30 | 21.43 | 14.02 |
| 6.50 | 21.69 | 17.77 |
| 6.70 | 22.68 | 21.24 |
| 6.90 | 22.81 | 24.21 |
| 7.00 | 23.07 | 25.56 |

S11 Forward Reflection
Impedance



PIN FUNCTIONS

RF_{IN} (Pin 1): RF Input Voltage. Referenced to V_{CC} . A coupling capacitor must be used to connect to the RF signal source. The frequency range is 300MHz to 7GHz. This pin has an internal 500Ω termination, an internal Schottky diode detector and a peak detector capacitor.

GND (Pin 2): Ground.

$\overline{\text{SHDN}}$ (Pin 3): Shutdown Input. A logic low on the $\overline{\text{SHDN}}$ pin places the part in shutdown mode. A logic high enables the part. $\overline{\text{SHDN}}$ has an internal $160k$ pulldown resistor to

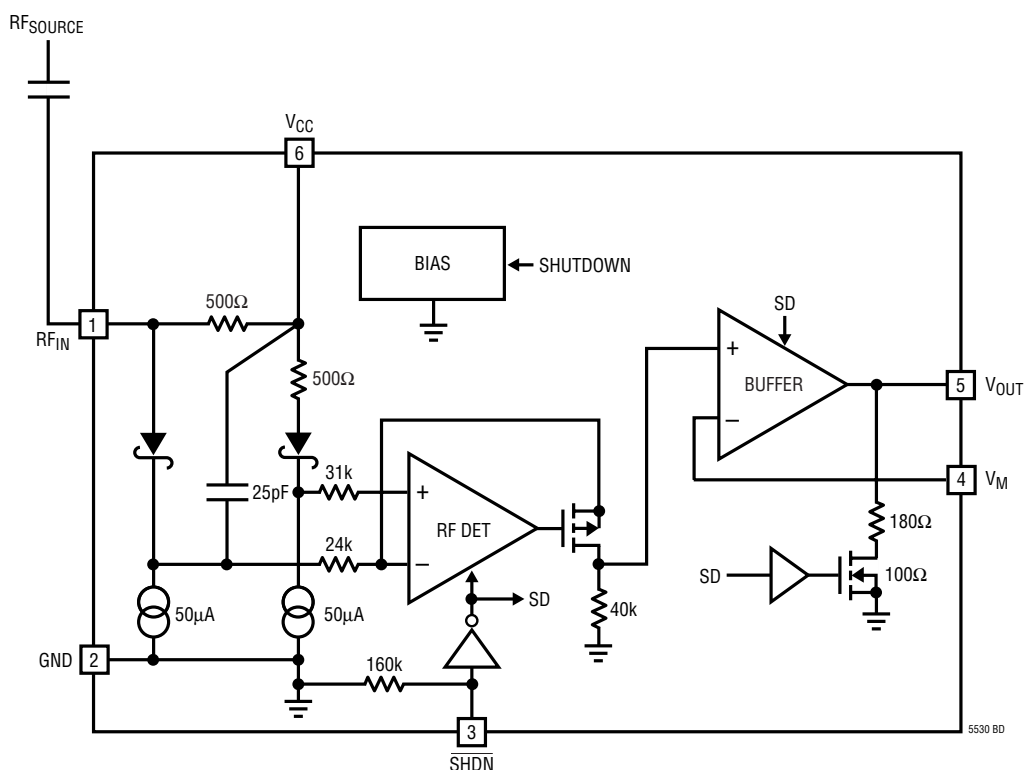
ensure that the part is in shutdown when no input is applied. In shutdown V_{OUT} is connected to ground via a 280Ω resistor.

V_M (Pin 4): Negative Input to Buffer Amplifier.

V_{OUT} (Pin 5): Detector Output.

V_{CC} (Pin 6): Power Supply Voltage, 2.7V to 6V. V_{CC} should be bypassed appropriately with ceramic capacitors.

BLOCK DIAGRAM



Downloaded from [Arrow.com](https://www.arrow.com).

APPLICATIONS INFORMATION

Applications

The LTC5530 can be used as a self-standing signal strength measuring receiver for a wide range of input signals from -32dBm to 10dBm for frequencies from 300MHz to 7GHz .

Operation at higher frequencies is achievable. Consult factory for more information.

The LTC5530 can be used as a demodulator for AM and ASK modulated signals with data rates up to 2MHz . Depending on specific application needs, the RSSI output can be split between two branches, providing AC-coupled

data (or audio) output and DC-coupled RSSI output for signal strength measurements and AGC.

The LTC5530 can be used for RF power detection and control. Figure 1 is an example of transmitter power control, using the LTC5530 with a capacitive tap to the power amplifier. A 0.5pF capacitor ($C1$) followed by a 200Ω resistor ($R1$) forms a coupling circuit with about 20dB loss at 900MHz referenced to the LTC5530 RF input pin. In the actual product implementation, component values for the capacitive tap may be different depending on parts placement, PCB parasitics and parameters of the antenna.

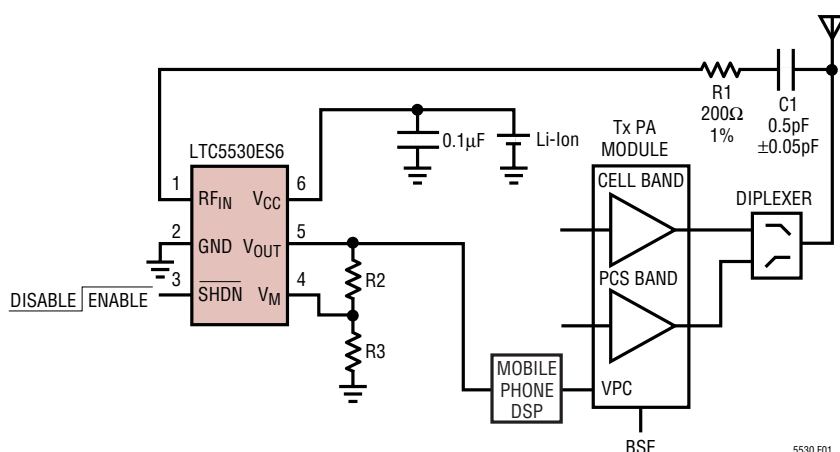
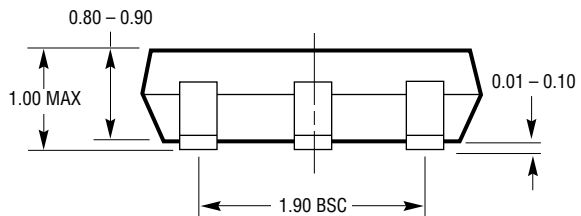
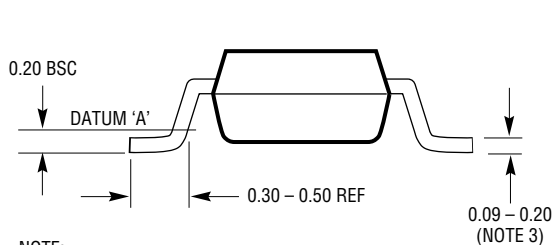
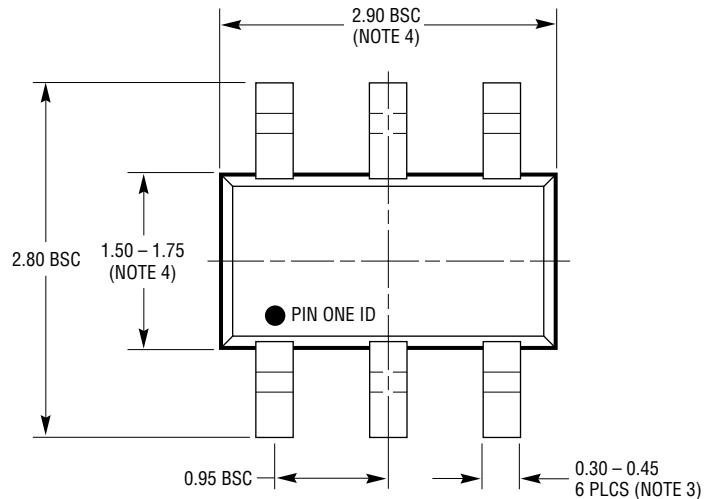
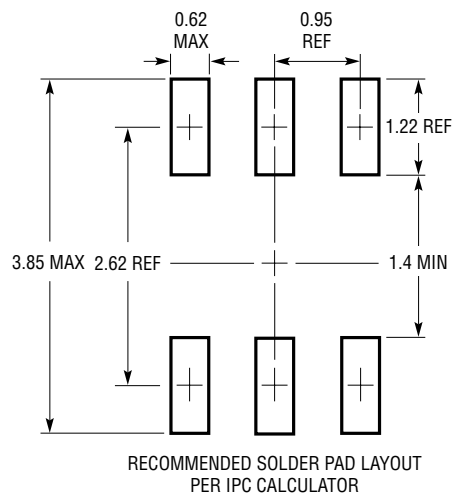


Figure 1. Mobile Phone Tx Power Control Application with a Capacitive Tap

PACKAGE DESCRIPTION

S6 Package
6-Lead Plastic TSOT-23
 (Reference LTC DWG # 05-08-1636)



S6 TSOT-23 0302

- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
 2. DRAWING NOT TO SCALE
 3. DIMENSIONS ARE INCLUSIVE OF PLATING
 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
 6. JEDEC PACKAGE REFERENCE IS MO-193

RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|-----------------------------|--|--|
| Infrastructure | | |
| LT5511 | High Linearity Upconverting Mixer | RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer |
| LT5512 | DC-3GHz High Signal Level Downconverting Mixer | DC to 3GHz, 21dBm IIP3, Integrated LO Buffer |
| LT5515 | 1.5GHz to 2.5GHz Direct Conversion Quadrature Demodulator | 20dBm IIP3, Integrated LO Quadrature Generator |
| LT5516 | 0.8GHz to 1.5GHz Direct Conversion Quadrature Demodulator | 21.5dBm IIP3, Integrated LO Quadrature Generator |
| LT5517 | 40MHz to 900MHz Direct Conversion Quadrature Demodulator | 21dBm IIP3, Integrated LO Quadrature Generator |
| LT5519 | 0.7GHz to 1.4GHz High Linearity Upconverting Mixer | 17.1dBm IIP3, 50Ω Single Ended RF and LO Ports |
| LT5520 | 1.3GHz to 2.3GHz High Linearity Upconverting Mixer | 15.9dBm IIP3, 50Ω Single Ended RF and LO Ports |
| LT5522 | 600MHz to 2.7GHz High Linearity Downconverting Mixer | 4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz, NF = 12.5dB, 50Ω Single-Ended RF and LO Ports |
| RF Power Detectors | | |
| LT5504 | 800MHz to 2.7GHz RF Measuring Receiver | 80dB Dynamic Range, Temperature Compensated, 2.7V to 5.25V Supply |
| LTC®5505 | 300MHz to 3GHz RF Power Detectors | LTC5505-1: -28dBm to 18dBm Range, LTC5505-2: -32dBm to 12dBm Range, Temperature Compensated, 2.7V to 6V Supply |
| LTC5507 | 100kHz to 1000MHz RF Power Detector | -34dBm to 14dBm Range, Temperature Compensated, 2.7V to 6V Supply |
| LTC5508 | 300MHz to 7GHz RF Power Detector | -32dBm to 12dBm Range, Temperature Compensated, SC70 Package |
| LTC5509 | 300MHz to 3GHz RF Power Detector | 36dB Dynamic Range, Temperature Compensated, SC70 Package |
| LTC5531 | 300MHz to 7GHz Precision RF Power Detector | Precision V_{OUT} Offset Control and Shutdown |
| LTC5532 | 300MHz to 7GHz Precision RF Power Detector | Precision V_{OUT} Offset Control, Adjustable Gain and Offset |
| RF Building Blocks | | |
| LT5500 | 1.8GHz to 2.7GHz Receiver Front End | 1.8V to 5.25V Supply, Dual-Gain LNA, Mixer, LO Buffer |
| LT5502 | 400MHz Quadrature IF Demodulator with RSSI | 1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range |
| LT5503 | 1.2GHz to 2.7GHz Direct IQ Modulator and Upconverting Mixer | 1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth |
| LT5506 | 500MHz Quadrature IF Demodulator with VGA | 1.8V to 5.25V Supply, 40MHz to 500MHz IF, -4dB to 57dB Linear Power Gain, 8.8MHz Baseband Bandwidth |
| LT5546 | 500MHz Quadrature IF Demodulator with VGA and 17MHz Baseband Bandwidth | 17MHz Baseband Bandwidth, 40MHz to 500MHz IF, 1.8V to 5.25V Supply, -7dB to 56dB Linear Power Gain |
| RF Power Controllers | | |
| LTC1757A | RF Power Controller | Multiband GSM/DCS/GPRS Mobile Phones |
| LTC1758 | RF Power Controller | Multiband GSM/DCS/GPRS Mobile Phones |
| LTC1957 | RF Power Controller | Multiband GSM/DCS/GPRS Mobile Phones |
| LTC4400 | SOT-23 RF PA Controller | Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW |
| LTC4401 | SOT-23 RF PA Controller | Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW |
| LTC4403 | RF Power Controller for EDGE/TDMA | Multiband GSM/GPRS/EDGE Mobile Phones, 250kHz Loop BW |